



### 60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

# **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> T <sub>C</sub> = +25°C
60V	$10m\Omega$ @ $V_{GS} = 10V$	89.5A
607	$13.5 \text{m}\Omega$ @ V <sub>GS</sub> = $4.5 \text{V}$	77A

## **Description**

This MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

# **Applications**

- High frequency switching
- Sync. rectifications
- DCDC converters

### **Features**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes Power Losses
- Low Q<sub>G</sub> Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

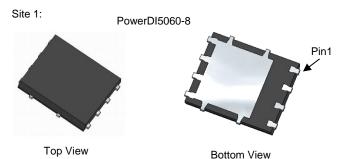
https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

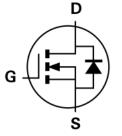
### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- · Weight: 0.097 grams (Approximate)

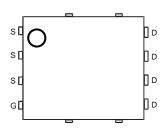


PowerDI5060-8/SWP (Type UX)

Site 2:



Internal Schematic



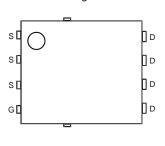
Top View Pin Configuration



**Bottom View** 

G

Internal Schematic



Top View Pin Configuration

Notes:

Top View

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



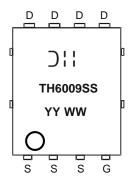
## **Ordering Information** (Note 4)

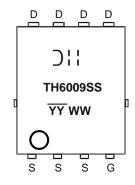
Part Number	Pankaga	Packing		
Part Number	Package	Qty.	Carrier	
DMTH6009SPS-13	PowerDI5060-8	2,500	Tape & Reel	
DMTH6009SPS-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Note:

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**





⊃;; = Manufacturer's Code Marking TH6009SS = Product Type Marking Code YYWW = Date Code Marking YY or YY = Year (ex: 23 = 2023) WW = Week (01 to 53)

## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage		$V_{GSS}$	±20	V
Continuous Drain Current (Note 5)	$T_A = +25$ °C $T_A = +100$ °C	ΙD	12.9 9.1	Α
Continuous Drain Current (Note 6)	T <sub>C</sub> = +25°C T <sub>C</sub> = +100°C	ID	89.5 63.3	А
Maximum Continuous Body Diode Forward Current (Note 6)		Is	80	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	350	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		I <sub>SM</sub>	350	Α
Avalanche Current, L = 0.1mH		las	20.3	Α
Avalanche Energy, L = 0.1mH		Eas	20.6	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	53	°C/W
Total Power Dissipation (Note 6)	$T_C = +25^{\circ}C$	P <sub>D</sub>	136	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.1	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



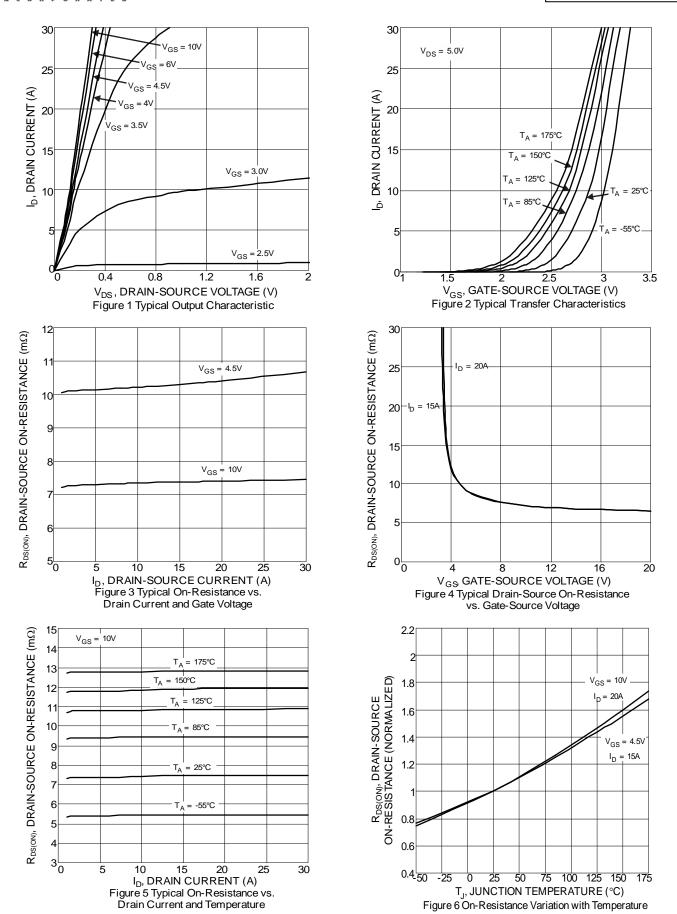
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	V <sub>G</sub> S = ±20V, V <sub>D</sub> S = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	1.2	_	2.8	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D		7.6	10	mΩ	Vgs = 10V, ID = 20A	
Static Dialii-Source Off-Resistance	RDS(ON)	_	10.7	13.5	11122	$V_{GS} = 4.5V, I_D = 15A$	
Diode Forward Voltage	VsD	_	0.9	1.2	V	V <sub>G</sub> S = 0V, I <sub>S</sub> = 20A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		1572			V 00V V 0V	
Output Capacitance	Coss		490	_	pF	$V_{DS} = 30V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Reverse Transfer Capacitance	Crss	_	50	_			
Gate Resistance	Rg	_	1.6	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (VGS = 10V)	Qg	_	29.3	_			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	13.9	_	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 13.5A	
Gate-Source Charge	Qgs	_	4.3	_	nc nc		
Gate-Drain Charge	Qgd	_	5.9	_			
Turn-On Delay Time	t <sub>D</sub> (ON)		5.4	_		$V_{DD} = 30V, V_{GS} = 10V,$ $R_{G} = 6\Omega, I_{D} = 13.5A$	
Turn-On Rise Time	t <sub>R</sub>		9.8	_			
Turn-Off Delay Time	tD(OFF)		28.1	_	ns		
Turn-Off Fall Time	tF		16.3	_			
Body Diode Reverse Recovery Time	trr	_	17.2	_	ns	1 40.54 31/31 4004/	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	25.1	_	nC	F = 13.5A, di/dt = 400A/μs	

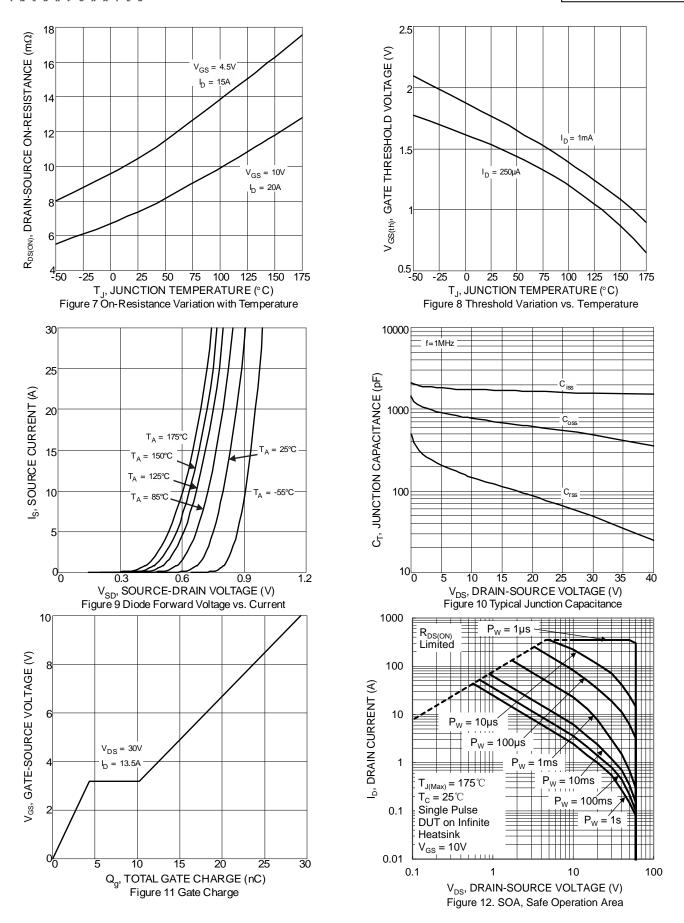
Notes:

<sup>7.</sup> Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.











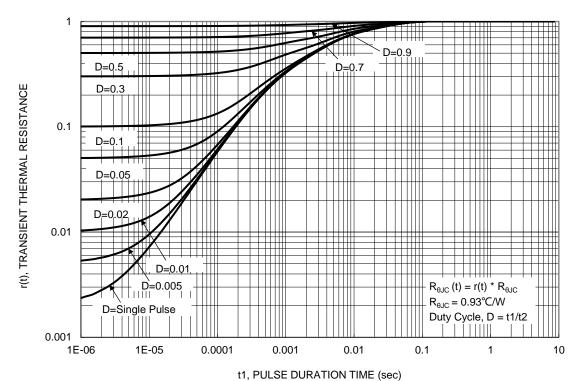


Figure 13. Transient Thermal Resistance

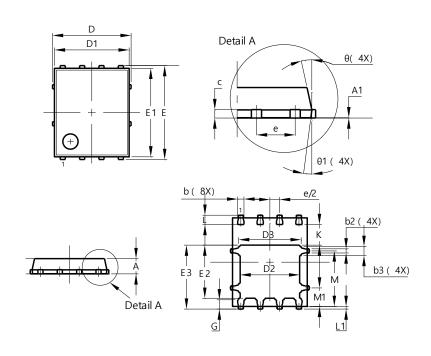


# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

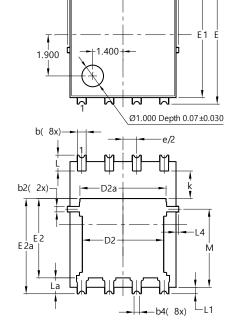
### PowerDI5060-8

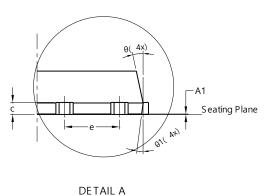


PowerDI5060-8				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0.00	0.05	-	
b	0.33	0.51	0.41	
b2	0.200	0.350	0.273	
b3	0.40	0.80	0.60	
С	0.230	0.330	0.277	
D	ļ	5.15 BSC	;	
D1	4.70	5.10	4.90	
D2	3.70	4.10	3.90	
D3	3.90	4.30	4.10	
Е	•	6.15 BSC	,	
E1	5.60	6.00	5.80	
E2	3.28	3.68	3.48	
E3	3.99	4.39	4.19	
е	•	1.27 BSC	;	
G	0.51	0.71	0.61	
K	0.51	-	-	
L	0.51	0.71	0.61	
L1	0.100	0.200	0.175	
M	3.235	4.035	3.635	
M1	1.00	1.40	1.21	
Θ	10°	12°	11°	
Θ1	6°	8°	7°	
All Dimensions in mm				

Site 2:

### PowerDI5060-8/SWP (Type UX)





DETAIL A

PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4		).25REF		
С	0.230	0.330	0.277	
D		.15 BS0		
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
Е	6	.40 BS0		
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1.27BSC			
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0.050REF			
L4	0.025	0.225	0.125	
M	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

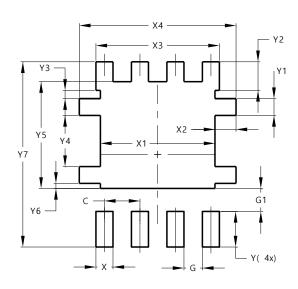


# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

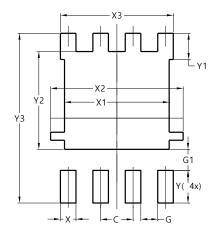
#### PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Υ	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

### PowerDI5060-8/SWP (Type UX)



Dimensions	Value
פווטופווטווט	(in mm)
C	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	5.190
Х3	4.420
Υ	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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